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Application Number	10/810,962				
Filing Date	March 26, 2004				
First Named Inventor	RUECKES et al.				
Art Unit	2827				
Examiner Name	IBA Huan Itrang				
Attorney Docket Number	112020.145YS2 NAN-21				

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	STATEMENT (Use as many s			Application No. Filing Date First Named Inventor Art Unit Examiner Name	10/8/0,962 3/26/04 RUECKES et al. 2827 IBA Huan Hoang
Sheet	2 /	of	· 4	Attorney Docket Number	112020.145YS2 NAN-21

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PTO/SB/08A (08-03) Approved for use through 07/31/2006. OMB 0651-0031

112020.145YS2 NAN-21

U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE ection Act of 1995, no person are required to respond to a collection of information unless it contains a valid OMB control number. Substitute for form Complete if Known **Application Number** 10/810,962 INFORMATION DISCLOSURE Filing Date March 26, 2004 STATEMENT BY APPLICANT First Named Inventor RUECKES et al (Use as many sheets as necessary) Art Unit Examiner Name

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P E INFORMATION DISCLOSURE	Application No.	10/810,962	
APR 1 5 2005 (Use as many sheets as necessary)	Filing Date	March 26, 2004	
	First Named Inventor	RUECKES, et al.	
	Art Unit	2018-2827	
	Examiner Name	IBA Huan Hoang	
1 of 1	Attorney Docket Number	112020.145 US2 NAN-21	

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Examiner Initials*	Cite No.1	Document Number Number-Kind Code ^{2(1 known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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